NSN 5962-01-180-3303

Memory Microcircuit - Page 1 of 1



view Online at https://aerobasegroup.com/nsn/5962-01-160-3303
Body Length:
Between 0.690 inches and 0.725 inches
Body Width:
Between 0.620 inches and 0.660 inches
Body Height:
Between 0.070 inches and 0.115 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
W/enable and low power and schottky
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
18 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
20.00 nanoseconds propagation delay time, low to high level output and 20.00 nanoseconds propagation delay time, high to low leve
output
Memory Device Type:
Ram
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 flat leads
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli

Fiig:

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